### 120SPC045/A



Technical Data Data Sheet N1156, Rev. - Green Products

# Power Surface Mount Schottky Rectifier (45V, 120Amp)

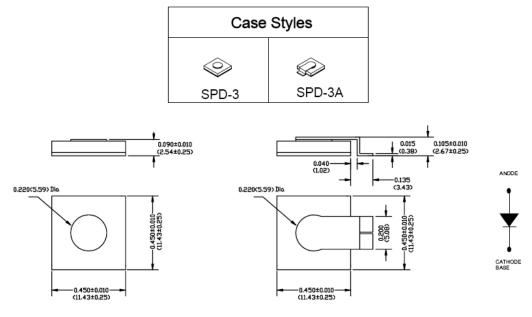
#### **Applications:**

- Switching power supply
- Converters
- Reverse battery protection
- Redundant power subsystems
- Many other high current AC/DC power supplies

#### Features:

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- Low reverse leakage current
- High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Mechanical Dimensions: In Inches / mm









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### Maximum Ratings:

Characteristics	Symbol	Condition	Max.	_ Units _
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form	120	A
Peak One Cycle Non-Repetitive Surge Current(per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	1650	А
Non-Repetitive Avalanche Energy(per leg)	E <sub>AS</sub>	T <sub>J</sub> =25℃,I <sub>AS</sub> =11A, L=1.2mH	76	mJ
Repetitive Avalanche Current(per leg)	I <sub>AR</sub>	$I_{AS}$ decaying linearly to 0 in 1 $\mu$ sec Frequency limited by $T_J$ max. $V_A$ =1.5 $\times$ $V_R$	11	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 120A, Pulse, T <sub>J</sub> = 25 °C	0.60	V
	V <sub>F2</sub>	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.57	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R$ , Pulse, T <sub>J</sub> = 25 °C	9.0	mA
	I <sub>R2</sub>	$@V_R = rated V_R$ ,Pulse, T <sub>J</sub> = 125 °C	420	mA
Junction Capacitance	CJ	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz ,Vsig=50mV(p-p)	4800	pF

\* Pulse Width < 300µs, Duty Cycle <2%

### **Thermal-Mechanical Specifications:**

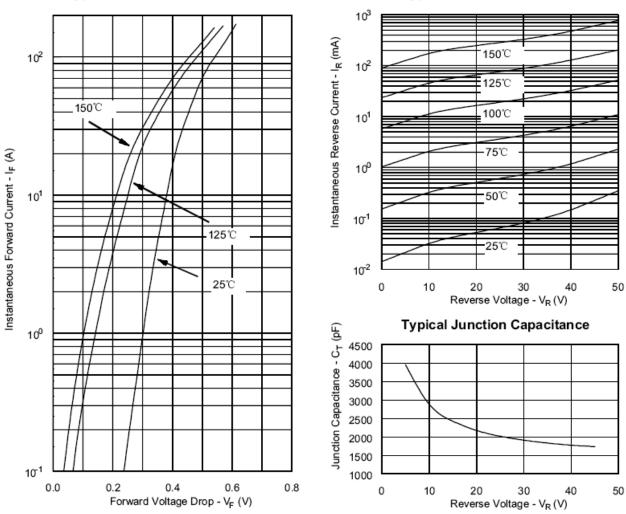
Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	TJ	-	-55 to +150	°C	
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C	
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	0.20	°C/W	
Case Style	SPD-3/A				

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**Typical Forward Characteristics** 

#### **Typical Reverse Characteristics**



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